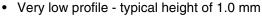
New Product

SS1P3 & SS1P4

Vishay General Semiconductor

High Current Density Surface Mount Schottky Barrier Rectifiers

FEATURES • Very low p



- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

(Note: These devices are not Q101 qualified.)

MECHANICAL DATA

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS1P3	SS1P4	UNIT	
Device marking code		13	14		
Maximum repetitive peak reverse voltage	V _{RRM}	30	40	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	1.0		А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30		А	
Non-repetitive avalanche energy at I _{AS} = 1.5 A, L = 10 mH, T _J = 25 $^\circ\text{C}$	E _{AS}	10		mJ	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150		°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	SS1P3	SS1P4	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 1.0 A I _F = 1.0 A	T _J = 25 °C T _J = 125 °C	V _F	0.50 0.40	0.53 0.45	V
Maximum reverse current at rated $V_R^{(2)}$		T _J = 25 °C T _J = 125 °C	I _R	150 15		μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	70		pF

Notes:

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle (2) Pulse test: Pulse width \leq 40 ms



RoHS

COMPLIANT



DO-220AA (SMP)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	1 A			
V _{RRM}	30 V, 40 V			
I _{FSM}	30 A			
E _{AS}	10 mJ			
V _F	0.40 V, 0.45 V			
T _J max.	150 °C			

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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SS1P3	SS1P4	UNIT		
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL} R _{θJC}	105 15 25		°C/W		

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS1P3-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel	
SS1P3-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

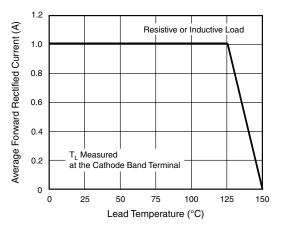


Figure 1. Maximum Forward Current Derating Curve

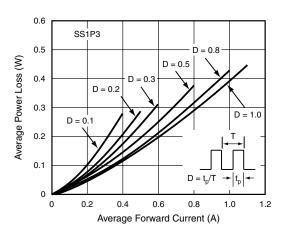


Figure 2. Forward Power Loss Characteristics

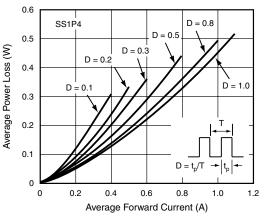


Figure 3. Forward Power Loss Characteristics

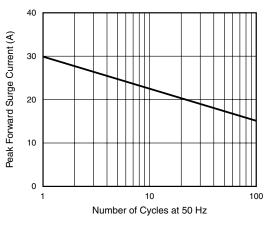


Figure 4. Typical Instantaneous Forward Characteristics



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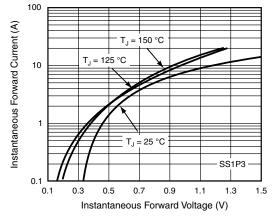


Figure 5. Typical Instantaneous Forward Characteristics

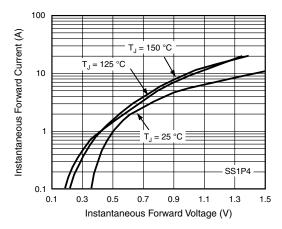


Figure 6. Typical Instantaneous Forward Characteristics

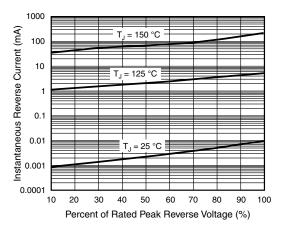


Figure 7. Typical Reverse Leakage Characteristics

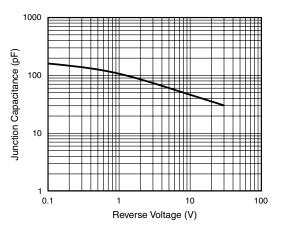


Figure 8. Typical Junction Capacitance

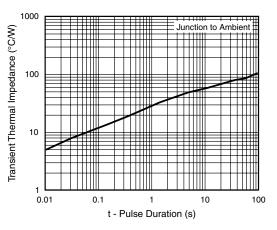
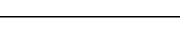


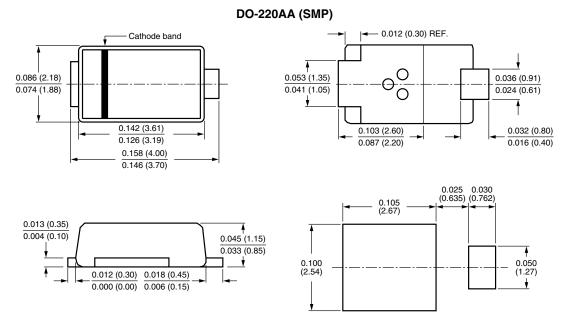
Figure 9. Typical Transient Thermal Impedatnce





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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Vishay

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